

INFORMATION DISCLOSURE CITATION FORM FOR PATENT APPLICATION (FORM PTO-1449) (Substitute)		Docket No.: 909A.0128.U1(US)		Serial No.: Unknown	
		Applicant(s): Joshi et al.			
		Filing Date: Herewith		Group: Unknown	
U.S. PATENT DOCUMENTS					
Examiner Initials	Document Number (Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name of Patentee or Applicant	Class	Sub-class
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	US-5759898	06-02-1998	Ek et al.	438	291
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Examiner Initials	Document Number (Country Code-Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name Of Patentee of Applicant	Translation? Yes/No/n/a	
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OTHER DOCUMENTS (Author (Capitalize), Title, Date, Pages, Etc., if known)					
	IEEE Transactions on Electron Devices, "Electron and Hole Mobility Enhancement in Strained SOI by Wafer Bonding", Huang et al., Vol. 49, No. 9, September 2002.				
	IBM Journal Research & Development, "Process requirements for continued scaling of CMOS-the need and prospects for atomic-level manipulation", P.D. Agnello, Vol. 46, No. 2/3, March/May 2002.				
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Examiner's Signature:			Date Considered:		
Initial if reference was considered, whether or not citation is in conformance with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).					